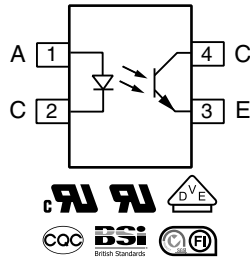
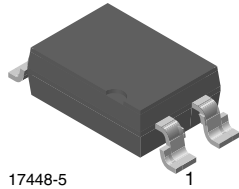


Optocoupler, Phototransistor Output, High Reliability, 5300 V_{RMS}



FEATURES

- Excellent CTR linearity depending on forward current
- Isolation test voltage, 5300 V_{RMS}
- Fast switching times
- Low CTR degradation
- Low coupling capacitance
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT

DESCRIPTION

The SFH6156 features a variety of transfer ratios, low coupling capacitance and high isolation voltage. This coupler has a GaAs infrared diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic SMD package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

APPLICATIONS

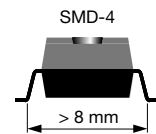
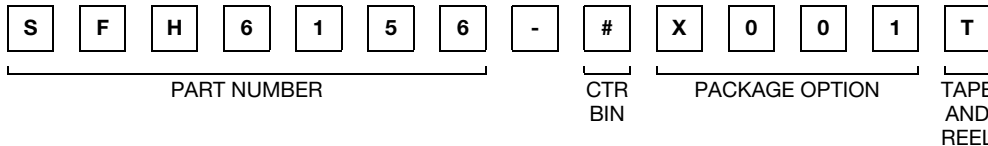
- Switchmode power supply
- Telecom
- Battery powered equipment

AGENCY APPROVALS

The safety application model number covering all products in this datasheet is SFH615A. This model number should be used when consulting safety agency documents.

- UL1577, file no. E52744 system code H or J, double protection
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1
- cUL tested to CSA 22.2 bulletin 5A
- BSI IEC 60950, IEC 60065
- FIMKO EN6005, EN60950-1
- CQC G8898-2011

ORDERING INFORMATION



| AGENCY CERTIFIED/PACKAGE | CTR (%) | | | |
|--------------------------------------|-----------------|------------------|-------------------|-------------------|
| | 10 mA | | | |
| UL, cUL, BSI, FIMKO, CQC | 40 to 80 | 63 to 125 | 100 to 200 | 160 to 320 |
| SMD-4, 100 mil, pitch | SFH6156-1 | SFH6156-2 | SFH6156-3 | SFH6156-4 |
| | SFH6156-1T | SFH6156-2T | SFH6156-3T | SFH6156-4T |
| VDE, UL, cUL, BSI, FIMKO, CQC | 40 to 80 | 63 to 125 | 100 to 200 | 160 to 320 |
| SMD-4, 100 mil, pitch | SFH6156-1X001 | SFH6156-2X001 | SFH6156-3X001 | SFH6156-4X001 |
| | SFH6156-1X001T | SFH6156-2X001T | SFH6156-3X001T | SFH6156-4X001T |

| ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified) | | | | |
|--|----------------------------------|------------|-------------|--------------------|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT |
| INPUT | | | | |
| Reverse voltage | | V_R | 6 | V |
| DC forward current | | I_F | 60 | mA |
| Surge forward current | $t_p \leq 10\text{ }\mu\text{s}$ | I_{FSM} | 2.5 | A |
| OUTPUT | | | | |
| Collector emitter voltage | | V_{CEO} | 70 | V |
| Emitter collector voltage | | V_{ECO} | 7 | V |
| Collector current | | I_C | 50 | mA |
| | $t_p \leq 1\text{ ms}$ | I_C | 100 | mA |
| COUPLER | | | | |
| Storage temperature range | | T_{stg} | -55 to +150 | $^{\circ}\text{C}$ |
| Ambient temperature range | | T_{amb} | -55 to +100 | $^{\circ}\text{C}$ |
| Soldering temperature ⁽¹⁾ | max. 10 s | T_{slid} | 260 | $^{\circ}\text{C}$ |

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- ⁽¹⁾ Refer to reflow profile for soldering conditions for surface mounted devices (SMD).

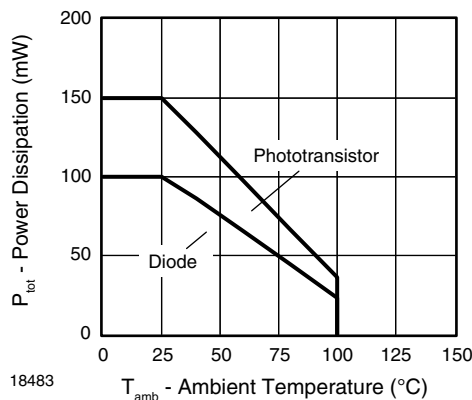
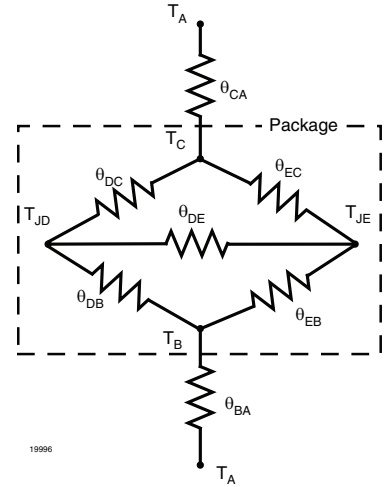


Fig. 1 - Permissible Power Dissipation vs. Ambient Temperature

| THERMAL CHARACTERISTICS | | | |
|---|---------------|-------|------|
| PARAMETER | SYMBOL | VALUE | UNIT |
| LED power dissipation | P_{diss} | 100 | mW |
| Output power dissipation | P_{diss} | 150 | mW |
| Maximum LED junction temperature | $T_{jmax.}$ | 125 | °C |
| Maximum output die junction temperature | $T_{jmax.}$ | 125 | °C |
| Thermal resistance, junction emitter to board | θ_{EB} | 173 | °C/W |
| Thermal resistance, junction emitter to case | θ_{EC} | 149 | °C/W |
| Thermal resistance, junction detector to board | θ_{DB} | 111 | °C/W |
| Thermal resistance, junction detector to case | θ_{DC} | 127 | °C/W |
| Thermal resistance, junction emitter to junction detector | θ_{ED} | 95 | °C/W |
| Thermal resistance, board to ambient ⁽¹⁾ | θ_{BA} | 195 | °C/W |
| Thermal resistance, case to ambient ⁽¹⁾ | θ_{CA} | 3573 | °C/W |


Notes

- The thermal model is represented in the thermal network below. Each resistance value given in this model can be used to calculate the temperatures at each node for a given operating condition. The thermal resistance from board to ambient will be dependent on the type of PCB, layout and thickness of copper traces. For a detailed explanation of the thermal model, please reference Vishay's thermal characteristics of optocouplers application note.

⁽¹⁾ For 2 layer FR4 board (4" x 3" x 0.062")

| ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ °C}$, unless otherwise specified) | | | | | | | |
|---|--|-----------|-------------|------|------|------|---------------|
| PARAMETER | TEST CONDITION | PART | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| INPUT | | | | | | | |
| Forward voltage | $I_F = 60\text{ mA}$ | | V_F | - | 1.25 | 1.65 | V |
| Reverse current | $V_R = 6\text{ V}$ | | I_R | - | 0.01 | 10 | μA |
| Capacitance | $V_R = 0\text{ V}$, $f = 1\text{ MHz}$ | | C_O | - | 13 | - | pF |
| OUTPUT | | | | | | | |
| Collector emitter capacitance | $V_{CE} = 5\text{ V}$, $f = 1\text{ MHz}$ | | C_{CE} | - | 5.2 | - | pF |
| Collector emitter leakage current | $V_{CE} = 10\text{ V}$ | SFH6156-1 | I_{CEO} | - | 2 | 50 | nA |
| | | SFH6156-2 | I_{CEO} | - | 2 | 50 | nA |
| | | SFH6156-3 | I_{CEO} | - | 5 | 100 | nA |
| | | SFH6156-4 | I_{CEO} | - | 5 | 100 | nA |
| COUPLER | | | | | | | |
| Collector emitter saturation voltage | $I_F = 10\text{ mA}$, $I_C = 2.5\text{ mA}$ | | V_{CEsat} | - | 0.25 | 0.4 | V |
| Coupling capacitance | | | C_C | - | 0.4 | - | pF |

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.



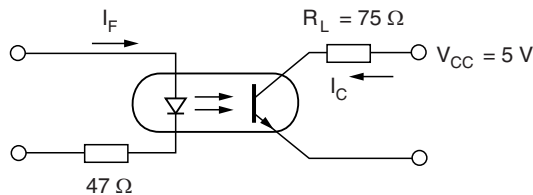
| CURRENT TRANSFER RATIO | | | | | | | |
|--------------------------------|---|-----------|--------|------|------|------|------|
| PARAMETER | TEST CONDITION | PART | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| I _C /I _F | I _F = 10 mA, V _{CE} = 5 V | SFH6156-1 | CTR | 40 | - | 80 | % |
| | | SFH6156-2 | CTR | 63 | - | 125 | % |
| | | SFH6156-3 | CTR | 100 | - | 200 | % |
| | | SFH6156-4 | CTR | 160 | - | 320 | % |
| | I _F = 1 mA, V _{CE} = 5 V | SFH6156-1 | CTR | 13 | 30 | - | % |
| | | SFH6156-2 | CTR | 22 | 45 | - | % |
| | | SFH6156-3 | CTR | 34 | 70 | - | % |
| | | SFH6156-4 | CTR | 56 | 90 | - | % |

| SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | | |
|--|--|-----------|------------------|------|------|------|------|
| PARAMETER | TEST CONDITION | PART | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| NON-SATURATED | | | | | | | |
| Turn-on time | I _F = 10 mA, V _{CC} = 5 V, R _L = 75 Ω | | t _{on} | - | 3 | - | μs |
| Rise time | I _F = 10 mA, V _{CC} = 5 V, R _L = 75 Ω | | t _r | - | 2 | - | μs |
| Turn-off time | I _F = 10 mA, V _{CC} = 5 V, R _L = 75 Ω | | t _{off} | - | 2.3 | - | μs |
| Fall time | I _F = 10 mA, V _{CC} = 5 V, R _L = 75 Ω | | t _f | - | 2 | - | μs |
| Cut-off frequency | I _F = 10 mA, V _{CC} = 5 V, R _L = 75 Ω | | f _{CO} | - | 250 | - | kHz |
| SATURATED | | | | | | | |
| Turn-on time | I _F = 20 mA | SFH6156-1 | t _{on} | - | 3 | - | μs |
| | I _F = 10 mA | SFH6156-2 | t _{on} | - | 4.2 | - | μs |
| | | SFH6156-3 | t _{on} | - | 4.2 | - | μs |
| | I _F = 5 mA | SFH6156-4 | t _{on} | - | 6 | - | μs |
| Rise time | I _F = 20 mA | SFH6156-1 | t _r | - | 2 | - | μs |
| | I _F = 10 mA | SFH6156-2 | t _r | - | 3 | - | μs |
| | | SFH6156-3 | t _r | - | 3 | - | μs |
| | I _F = 5 mA | SFH6156-4 | t _r | - | 4 | - | μs |
| Turn-off time | I _F = 20 mA | SFH6156-1 | t _{off} | - | 18 | - | μs |
| | I _F = 10 mA | SFH6156-2 | t _{off} | - | 23 | - | μs |
| | | SFH6156-3 | t _{off} | - | 23 | - | μs |
| | I _F = 5 mA | SFH6156-4 | t _{off} | - | 25 | - | μs |
| Fall time | I _F = 20 mA | SFH6156-1 | t _f | - | 11 | - | μs |
| | I _F = 10 mA | SFH6156-2 | t _f | - | 14 | - | μs |
| | | SFH6156-3 | t _f | - | 14 | - | μs |
| | I _F = 5 mA | SFH6156-4 | t _f | - | 15 | - | μs |

| SAFETY AND INSULATION RATINGS | | | | |
|--|--|------------|----------------|--------------------|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT |
| Climatic classification | According to IEC 68 part 1 | | 55/100/21 | |
| Comparative tracking index | | CTI | 175 | |
| Maximum rated withstanding isolation voltage | t = 1 min | V_{ISO} | 4420 | V_{RMS} |
| Maximum transient isolation voltage | | V_{IOTM} | 10 000 | V |
| Maximum repetitive peak isolation voltage | | V_{IORM} | 890 | V |
| Isolation resistance | $V_{IO} = 500\text{ V}, T_{amb} = 25\text{ }^{\circ}\text{C}$ | R_{IO} | $\geq 10^{12}$ | Ω |
| | $V_{IO} = 500\text{ V}, T_{amb} = 100\text{ }^{\circ}\text{C}$ | R_{IO} | $\geq 10^{11}$ | Ω |
| Output safety power | | P_{SO} | 400 | mW |
| Input safety current | | I_{SI} | 275 | mA |
| Input safety temperature | | T_{SI} | 175 | $^{\circ}\text{C}$ |
| Creepage distance | | | ≥ 7 | mm |
| Clearance distance | | | ≥ 7 | mm |
| Insulation thickness | | DTI | ≥ 0.4 | mm |

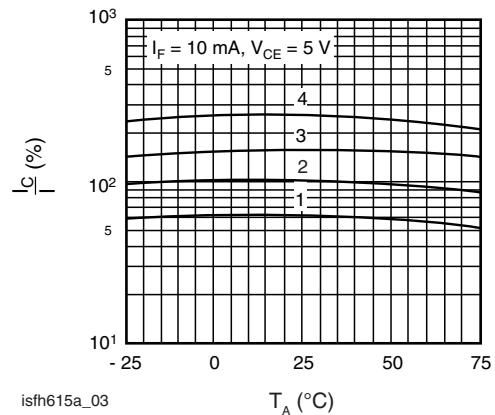
Note

- As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)


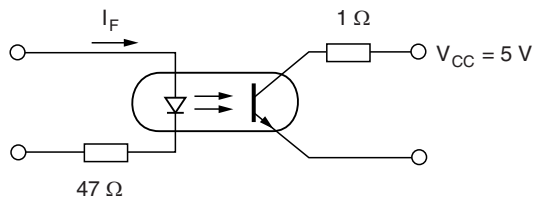
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Fig. 2 - Linear Operation (without saturation)



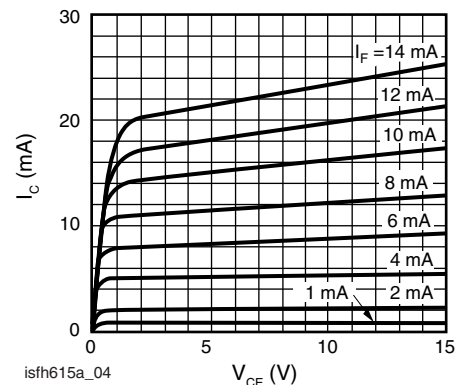
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Fig. 4 - Current Transfer Ratio (typ.) vs. Temperature



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Fig. 3 - Switching Operation (with saturation)



isfh615a_04

Fig. 5 - Output Characteristics (typ.) Collector Current vs. Collector Emitter Voltage

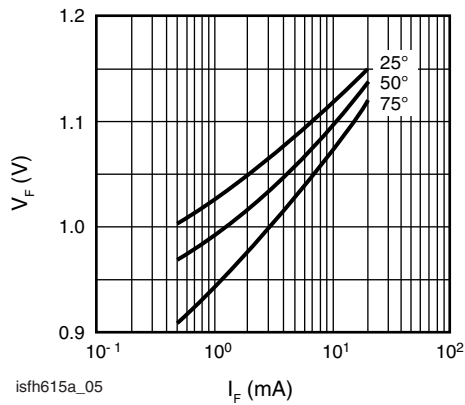


Fig. 6 - Diode Forward Voltage (typ.) vs. Forward Current

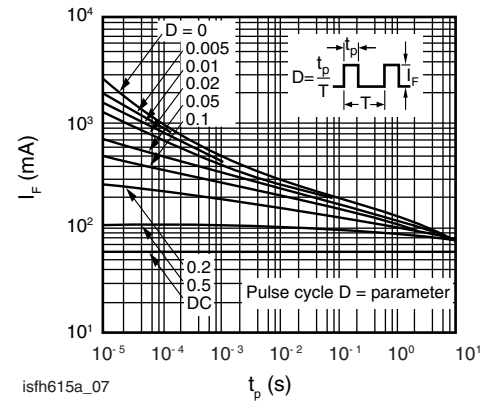


Fig. 8 - Permissible Pulse Handling Capability Forward Current vs. Pulse Width

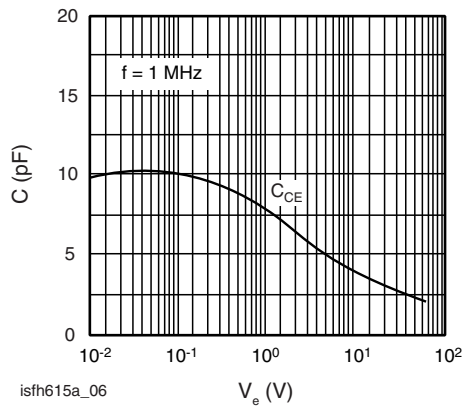
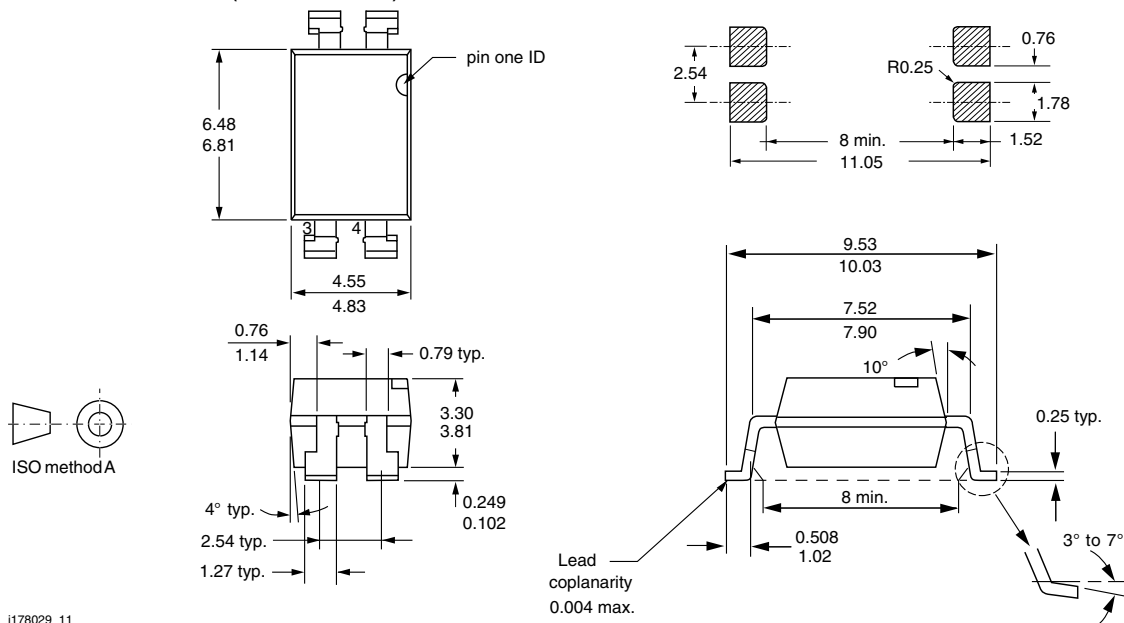


Fig. 7 - Transistor Capacitance (typ.) vs. Collector Emitter Voltage

PACKAGE DIMENSIONS (in millimeters)





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